Chapter 3: SPECIAL-PURPOSE DIODES

3–1 THE ZENER DIODE

- A **Zener diode** is a silicon *pn* junction device that is designed for operation in the reversebreakdown region(set by carefully controlling the doping level).
- A major application for zener diodes is voltage regulation by providing stable reference voltages for use in power supplies, voltmeters, and other instruments.
- In this section, you will see how the zener diode maintains a nearly constant dc voltage under the proper operating conditions.

After completing this Chapter, you should be able to:

- Describe the characteristics of a zener diode, its operation, equivalent circuits
- Define temperature coefficient and power dissipation and derating. to a zener diode
- Interpret zener diode datasheets
- Analyze zener regulation with a variable input voltage and with a variable load
- Discuss zener limiting
- Discuss another special purpose diodes

Breakdown Characteristics:

- As the reverse voltage (V_R) is increased to the breakdown point, the internal zener resistance (zener impedance Z_Z), begins to decrease as the reverse current (I_R) increases rapidly.
- The zener breakdown voltage (V_Z) remains essentially constant although it increases slightly as the zener current, I_Z , increases.

(a) Zener V-I characteristics





Zener Breakdown Types

Zener diodes are designed to operate in reverse breakdown. Two types of reverse breakdown in a zener diode:

- Avalanche effect: high reverse voltage & available in zeners with breakdown voltages > 5 V.
- Zener breakdown: low reverse voltages & available in zeners with breakdown voltages < 5 V.

Zener Regulation

- The zener diode maintains a nearly constant voltage across its terminals for values of reverse current ranging from I_{ZK} to I_{ZM} .
- There is a maximum current, I_{ZM} , above which the diode may be damaged due to excessive power
- V_Z , is usually specified on a datasheet at a value of reverse current called the Zener Test Current.

Zener Equivalent Circuits



Temperature Coefficient (TC):

- The percent change in Vz for each degree Celsius change
- For example: a 12 V zener diode with a positive temperature coefficient of TC= 0.01 (% / C) will exhibit a 1.2 mV increase in V_Z when the junction temperature increases one degree Celsius
- The formula for calculating the change in zener voltage for a given junction temperature change, for a specified temperature coefficient, is:



Vz: @ 25C, TC: temp coefficient, Δ T: change in temp

• In some cases, the temperature coefficient is expressed in mV/C rather than %/C, and in this case ΔVz can be calculated as:



EXAMPLE 3-2An 8.2 V zener diode (8.2 V at 25°C) has a positive temperature coefficient of
0.05%/°C. What is the zener voltage at 60°C?SolutionThe change in zener voltage is
 $\Delta V_Z = V_Z \times TC \times \Delta T = (8.2 \text{ V})(0.05\%/°C)(60°C - 25°C)$
= (8.2 V)(0.0005/°C)(35°C) = 144 mV
Notice that 0.05%/°C was converted to 0.0005/°C. The zener voltage at 60°C is
 $V_Z + \Delta V_Z = 8.2 \text{ V} + 144 \text{ mV} = 8.34 \text{ V}$

Zener Power Dissipation

- Maximum dc power dissipation P_{D(max)}: maximum power that Zerner diodes are specified to operate.
- For example, the 1N746 zener is rated at a $P_{D(max)}$ of 500 mW.
- The dc power dissipation is determined by the formula:

$$P_{\rm D} = V_{\rm Z} I_{\rm Z}$$

Zener Power De-rating

- **Derating** is the operation of a device at less than its rated maximum capability in order to prolong its life.
- The maximum power dissipation of a zener diode is typically specified for temperatures at or below a certain value.
- Above the specified temperature, the maximum power dissipation is reduced according to a **derating factor** expressed in mV/C.
- The maximum derated power:

$$P_{\text{D(derated)}} = P_{\text{D(max)}} - (\text{mW/°C})\Delta T$$

Solution	$P_{D(derated)} = P_{D(max)} - (mW/^{\circ}C)\Delta T$ = 400 mW - (3.2 mW/^{\circ}C)(90^{\circ}C - 50^{\circ}C)